

## FEATURES/BENEFITS

- Pin and function compatible to the 74F573 74FCT573 and 74FCT573T
- Industrial temperature  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$
- CMOS power levels:  $<7.5\text{mW}$  static
- Available in DIP, SOIC, QSOP, ZIP, HQSOP
- Undershoot clamp diodes on all inputs
- TTL-compatible input and output levels
- Ground bounce controlled outputs
- Reduced output swing of 0-3.5V
- Military product compliant to MIL-STD-883, Class B

### FCT-T 573T

- JEDEC-FCT spec compatible
- Std, A, and C speed grades with  $4.2\text{ns}$   $t_{PD}$  for C
- $I_{OL} = 48\text{mA}$  Ind.,  $32\text{mA}$  Mil.

### FCT-T 2573T

- Built-in  $25\Omega$  series resistor outputs reduce reflection and other system noise
- Std, A, and C speed grades with  $4.2\text{ns}$   $t_{PD}$  for C
- $I_{OL} = 12\text{mA}$  Ind.

## DESCRIPTION

The QSFCT573T and QSFCT2573T are 8-bit high-speed CMOS TTL-compatible buffered latches with three-state outputs that are ideal for driving high capacitance loads such as memory and address buses. The 2573 devices are  $25\Omega$  resistor output versions useful for driving transmission lines and reducing system noise. The 2573 series parts can replace the 573 series to reduce noise in an existing design. All inputs have clamp diodes for undershoot noise suppression. All outputs have ground bounce suppression (see QSI Application Note AN-001), and outputs will not load an active bus when  $V_{CC}$  is removed from the device.

**Figure 1. Functional Block Diagram**

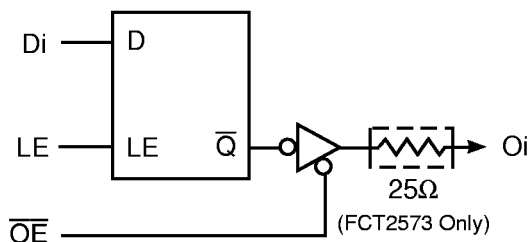


Figure 2. Pin Configurations (All Pins Top View)

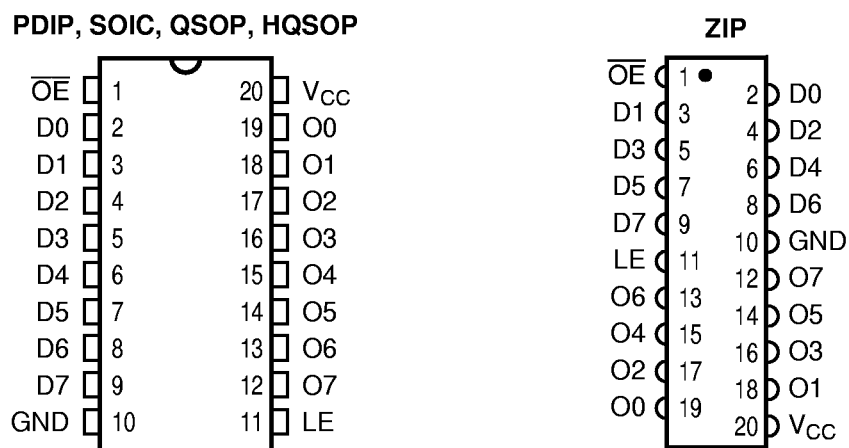


Table 1. Pin Description

Name	I/O	Description
Di	I	Data Inputs
O <sub>i</sub>	O	Data Outputs
LE	I	Latch Enable
$\overline{OE}$	I	Output Enable

Table 2. Function Table

$\overline{OE}$	Inputs LE	Di	Internal Q Value	Outputs O <sub>i</sub>	Function
H	X	X	X	Hi-Z	Disable Outputs
L	L	X	L	L	Enable Outputs
L	L	X	H	H	Enable Outputs
L	H	L	L	L	Pass Inputs
L	H	H	H	H	Pass Inputs
L	L	X	Q	Q	Hold Prior Data

**Table 3. Absolute Maximum Ratings**

Supply Voltage to Ground .....	-0.5V to 7.0V
DC Output Voltage $V_{OUT}$ .....	-0.5V to 7.0V
DC Input Voltage $V_{IN}$ .....	-0.5V to 7.0V
AC Input Voltage (for a pulse width $\leq 20$ ns) .....	-3.0V
DC Input Diode Current with $V_{IN} < 0$ .....	-20mA
DC Output Diode Current with $V_{OUT} < 0$ .....	-50mA
DC Output Current Max. Sink Current/Pin .....	120mA
Maximum Power Dissipation .....	0.5 watts
$T_{STG}$ Storage Temperature .....	-65° to 150°C

**Note:** Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to QSI devices that result in functional or reliability type failures.

**Table 4. Capacitance<sup>(1)</sup>**

$T_A = 25^\circ\text{C}$ ,  $f = 1\text{MHz}$ ,  $V_{IN} = 0\text{V}$ ,  $V_{OUT} = 0\text{V}$

Pins <sup>(2)</sup>	SOIC	QSOP	PDIP	ZIP	Unit
1-9, 11	4	4	5	7	pF
12-19	6	6	7	9	pF

**Notes:**

1. Capacitance is characterized but not tested.
2. Pin reference for 20-pin package.

**Table 5. Power Supply Characteristics**

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min	Max	Unit
$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$ , $\text{freq} = 0$ $0\text{V} \leq V_{IN} \leq 0.2\text{V}$ or $V_{CC}-0.2\text{V} \leq V_{IN} \leq V_{CC}$	—	1.5	mA
$\Delta I_{CC}$	Supply Current per Input @ TTL HIGH	$V_{CC} = \text{Max.}$ , $V_{IN} = 3.4\text{V}$ , $\text{freq} = 0^{(2)}$	—	2.0	mA
$Q_{CCD}$	Supply Current per Input per MHz	$V_{CC} = \text{Max.}$ , Outputs Open and Enabled One Bit Toggling @ 50% Duty Cycle Other Inputs at GND or $V_{CC}^{(3,4)}$	—	0.25	mA/MHz

**Notes:**

1. For conditions shown as Min. or Max., use the appropriate values specified under DC specifications.
2. Per TTL driven input ( $V_{IN} = 3.4\text{V}$ ).
3. For flip-flops,  $Q_{CCD}$  is measured by switching one of the data input pins so that the output changes every clock cycle. This is a measurement of device power consumption only and does not include power to drive load capacitance or tester capacitance. This parameter is guaranteed by design but not tested.
4.  $I_C$  can be computed using the above parameters as explained in the Technical Overview section.

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**Table 6. DC Electrical Characteristics Over Operating Range**

Industrial  $T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 5\%$

Military  $T_A = -55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 10\%$

Symbol	Parameter	Test Conditions	Min	Typ <sup>(1)</sup>	Max	Unit
$V_{IH}$	Input HIGH Voltage	Logic HIGH for All Inputs	2.0	—	—	V
$V_{IL}$	Input LOW Voltage	Logic LOW for All Inputs	—	—	0.8	V
$\Delta V_T$	Input Hysteresis	$V_{TLH} - V_{THL}$ for All Inputs	—	0.2	—	V
$ I_{IH} $ $ I_{IL} $	Input Current Input HIGH or LOW	$V_{CC} = \text{Max.}, 0 \leq V_{IN} < V_{CC}$	—	—	5	$\mu\text{A}$
$ I_{OZ} $	Off-State Output Current (Hi-Z)	$V_{CC} = \text{Max.}, 0 \leq V_{IN} \leq V_{CC}$	—	—	5	$\mu\text{A}$
$I_{OS}$	Short Circuit Current (FCT573)	$V_{CC} = \text{Max.}, V_{OUT} = \text{GND}^{(2,3)}$	-60	—	—	mA
$I_{OR}$	Current Drive (FCT2573 – 25 $\Omega$ )	$V_{CC} = \text{Min.}, V_{OUT} = 2.0\text{V}^{(3)}$	50	—	—	mA
$V_{IC}$	Input Clamp Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18\text{mA}, T_A = 25^{\circ}\text{C}^{(3)}$	—	-0.7	-1.2	V
$V_{OH}$	Output HIGH Voltage	$V_{CC} = \text{Min.},$ $I_{OH} = -12\text{mA}$ (MIL) $I_{OH} = -15\text{mA}$ (IND)	2.4 2.4	— —	— —	V
$V_{OL}$	Output LOW Voltage (FCT573)	$V_{CC} = \text{Min.},$ $I_{OL} = 32\text{mA}$ (MIL) $I_{OL} = 48\text{mA}$ (IND)	— —	— —	0.50 0.50	V
$V_{OL}$	Output LOW Voltage (FCT2573 – 25 $\Omega$ )	$V_{CC} = \text{Min.},$ $I_{OL} = 12\text{mA}$ (MIL) $I_{OL} = 12\text{mA}$ (IND)	— —	— —	0.50 0.50	V
$R_{OUT}$	Output Resistance (FCT2573 – 25 $\Omega$ )	$V_{CC} = \text{Min.},$ $I_{OL} = 12\text{mA}$ (MIL) $I_{OL} = 12\text{mA}$ (IND)	— 20	25 28	— 40	$\Omega$

**Notes:**

1. Typical values indicate  $V_{CC} = 5.0\text{V}$  and  $T_A = 25^{\circ}\text{C}$ .
2. Not more than one output should be shorted and the duration is  $\leq 1$  second.
3. These parameters are guaranteed by design but not tested.

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**Table 7. Switching Characteristics Over Operating Range**

Industrial  $T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 5\%$

Military  $T_A = -55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 10\%$

$C_{LOAD} = 50\text{pF}$ ,  $R_{LOAD} = 500\Omega$  unless otherwise noted.

Symbol	Description <sup>(1)</sup>		573 2573		573A 2573A		573C 2573C		Unit
			Min	Max	Min	Max	Min	Max	
$t_{PHL}$ $t_{PLH}$	Propagation Delay Data to Oi, 573	IND MIL	1.5 2	8 8.5	1.5 1.5	5.2 5.6	1.5 1.5	4.2 5.1	ns
$t_{PHL}$ $t_{PLH}$	Propagation Delay Data to Oi, 2573	IND MIL	1.5 2	8 8.5	1.5 1.5	5.2 5.6	1.5 1.5	4.2 5.1	ns
$t_{PHLE}$ $t_{PLHE}$	Propagation Delay LE to Oi, 573	IND MIL	2 2	13 14	2 2	8.5 9.8	2 2	5.5 8	ns
$t_{PHLE}$ $t_{PLHE}$	Propagation Delay LE to Oi, 2573	IND MIL	2 2	13 14	2 2	8.5 9.8	2 2	5.5 8	ns
$t_{PZH}$ $t_{PZL}$	Output Enable Time $\overline{OE}$ to Yi, 573	IND MIL	1.5 1.5	11 12.5	1.5 1.5	6.5 7.5	1.5 1.5	5.5 6.3	ns
$t_{PZH}$ $t_{PZL}$	Output Enable Time $\overline{OE}$ to Yi, 2573	IND MIL	1.5 1.5	11 12.5	1.5 1.5	6.5 7.5	1.5 1.5	6.5 7.5	ns
$t_{PLZ}$ $t_{PHZ}$	Output Disable Time <sup>(2)</sup> $\overline{OE}$ to Yi	IND MIL	1.5 1.5	7 8.5	1.5 1.5	5.5 6.5	1.5 1.5	5.0 5.9	ns
$t_S$	Data Setup Time Di to LE HIGH to LOW	IND MIL	2 2		2 2		2		ns
$t_H$	Data Hold Time Di to LE HIGH to LOW	IND MIL	1.5 1.5		1.5 1.5		1.5		ns
$t_W$	LE Pulse Width <sup>(2)</sup> HIGH to LOW	IND MIL	6 6		5 6		4		ns

**Notes:**

1. Minimums guaranteed but not tested for all parameters except  $t_S$  and  $t_H$ .
2. This parameter is guaranteed by design but not tested.
3. See Test Circuit and Waveforms.